

SK515B

Technical Data Data Sheet N0951, Rev. A RoHS 🗭

SK515B SCHOTTKY RECTIFIER



Circuit Diagram



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	150	V
Average Rectified Forward Current	lf (AV)	50% duty cycle $@T_c=145^{\circ}C$, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3ms, Half Sine pulse, T_c = 25 °C	120	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.85	0.93	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.72	0.80	V
Reverse Current*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.002	1.0	mA
	I _{R2}	$@V_R = rated V_{R,} T_J = 125 \circ C$	0.01	7.0	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	70	200	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 µs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	4.5	°C/W
Approximate Weight	wt	-	0.09	g

Ratings and Characteristics Curves

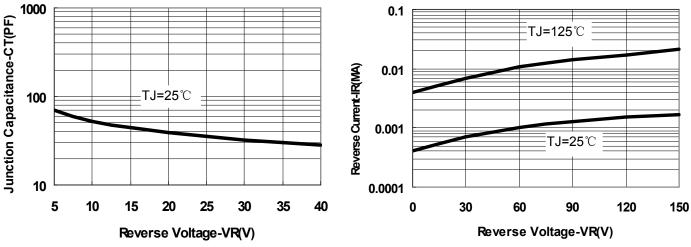


Fig.1-Typical Junction Capacitance



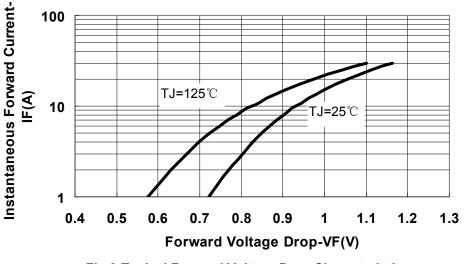


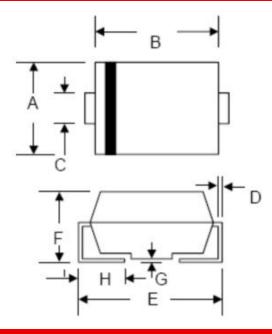
Fig.3-Typical Forward Voltage Drop Characteristics

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Mechanical Dimensions SMB



SYMDOL	Millimeters		Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	3.30	3.94	0.130	0.155
В	4.06	4.70	0.160	0.185
С	1.80	2.20	0.071	0.087
D	0.152	0.305	0.006	0.012
E	4.80	5.59	0.189	0.220
F	2.10	2.60	0.083	0.102
G	0.051	0.203	0.002	0.008
н	0.76	1.52	0.030	0.060

В 5 15 YY WW

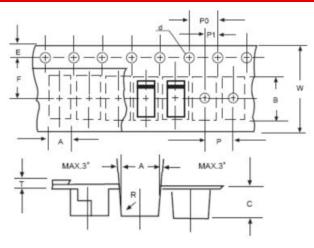
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Ordering Information

Device	Package	Shipping
SK515B	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification SMB



		1
	B515	h
40	XXXXX	μ
	1.100000.0000.000	

Marking Diagram

Where XXXXX is YYWWL

= Package type = Forward Current (5A) = Reverse Voltage (150V)

- = Year = Week = Lot Number

Cautions: Molding resin

SYMBOL	Millimeters			
STWBUL	Min.	Max.		
А	2.97	3.17		
В	5.70	5.90		
С	2.32	2.52		
d	1.40	1.60		
E	1.40	1.60		
F	5.60	5.70		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
Т	0.25	0.35		
W	11.80	12.20		

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